Hema C. P. Movva

hemacp@utexas.edu	Mar 2018, Austin, TX, US		2018, Austin, TX, USA	
Education	Ph.D., Electrica M.S.E., Electric B.Tech., Electric	al Engineering, The University of Texas at Au cal Engineering, The University of Texas at A cal Engineering, Indian Institute of Technolog	stin Expected 2018 ustin 2012 zy Bombay 2009	
Publications	HCP Movva et al., Tunable $\Gamma-K$ Valley Populations in Hole-Doped Trilayer WSe2, Phys. Rev. Lett. 120, 107703 (2018)			
	HCP Movva et al., Density-Dependent Quantum Hall States and Zeeman Splitting in Monolayer and Bilayer WSe ₂ , Phys. Rev. Lett. 118, 247701 (2017)			
	HCP Movva et al., High-Mobility Holes in Dual-Gated $\rm WSe_2$ Field-Effect Transistors, ACS Nano 9, 10402 (2015)			
Experience	Research Assistant, The University of Texas at AustinOngoing• Ph.D. advisors: Emanuel Tutuc, Sanjay Banerjee• Electrical contact engineering for transition metal dichalcogenide (TMD) FETs• Fabrication of dual-gated FETs using monolayer/few-layer TMDs such as WSe2• Quantum Hall effect measurements in high-quality TMD FETs• Tunneling phenomena in TMD heterostructure FETs			
	 Research Assistant, The University of Texas at Austin Aug '10 - May '12 M.S.E. advisor: Sanjay Banerjee Surface charge transfer doping of graphene for use in self-aligned FETs Fabricated graphene FETs with chemically doped source/drain access regions 			
	Engineer R&I • Modeled v • Developed • Managed	D , Solar Semiconductor Inc., Hyderabad, Indivattage losses in c-Si photovoltaic modules l distributed circuit models for c-Si solar cells sun simulators for solar cell and module chara	a Jun '09 - Aug '10 and modules acterization	
	 Circuit Design Intern, Texas Instruments, Bangalore, India May '08 - Aug '08 Designed a high-speed dynamic latch based voltage comparator Designed a 250 MSPS 6-bit SAR analog-to-digital convertor 			
Honors	Best Paper Award, 74th IEEE Device Research Conference201Best Poster Award, 73td IEEE Device Research Conference201Best Poster Award, 9th International Nanotechnology Conference (INC9)201Silver Medal, 37th International Physics Olympiad200National Talent Search scholarship, India200			
Service	Reviewer, IEEE Trans. Electron Dev., ACS Appl. Mater. Interfaces, NanoscaleMentor, Research Experience for High School Young ScholarsSum. '17President, Japan Karate Association of AustinMay '13 - May '15			
Skills	<u>Fabrication:</u> <u>Electrical:</u> <u>Metrology:</u> <u>Software:</u>	eation:Electron-beam lithography, standard cleanroom processingical:Semiconductor parameter analyzers, probe stations, He cryostatslogy:Atomic force microscopy, scanning electron microscopyare:MATLAB, LabVIEW, C		